# NSN 5961-00-893-9563

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#### **Inclosure Material:**

Metal

## **Overall Length:**

Between 0.500 inches and 0.560 inches

# **Overall Diameter:**

Between 1.240 inches and 1.280 inches

## Mounting Facility Quantity:

1

#### **Internal Configuration:**

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

#### Features Provided:

Hermetically sealed case

#### Thread Size:

0.312 inches

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 25.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

7.50 amperes source cutoff current

#### **Power Rating Per Characteristic:**

150.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

#### **Thread Series Designator:**

Unf

#### **Terminal Type And Quantity:**

1 threaded stud and 2 tab, solder lug

#### **Specification Data:**

81349-mil-s-19500/102 government specification

#### Shelf Life:

N/a

# Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

